

# Solid State General Communication Power Amplifier

**4070 – GCS4F4GTS**
**1291 – 1299 MHz / 800 Watts Pulse**

The GCS4F4GTS (SKU 4070) is suitable L-Band high power pulse and CW applications. This rack mount amplifier utilizes push-pull LDMOS power devices that provide high gain, wide dynamic range, low distortions and good linearity. Exceptional performance, long term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, built in high quality power supply, EMI/RFI filters, machined housings and qualified components. Empower RF's ISO9001 Quality Assurance Program assures consistent performance and the highest reliability.

- Solid-state linear design
- Instantaneous broadband
- Built in fast switching circuit.
- Small form factor and lightweight
- Suitable for CW & Pulse applications
- 50 ohm input/output impedance
- High reliability and ruggedness



Shown with Option Package 18

## ELECTRICAL SPECIFICATIONS @ 120V<sub>AC</sub>, 25°C, 50 Ω System

Characteristics	Rating	Min	Typ	Max	Units
Frequency Response	BW	1291		1299	MHz
Output Power (PEP)	P <sub>PULSE-PK</sub>	800			Watt
Power Output @ 1dB Gain Compression	P <sub>1dB</sub>	400			Watt
Input Power for Rated P <sub>SAT-PK</sub>	P <sub>IN</sub>		0		dBm
Power Gain @ P <sub>1dB</sub>	G <sub>1dB</sub>	58			dB
Gain Flatness	ΔG			±1.0	dB
Gain Adjustment Range	VVA	15	20		dB
Input Return Loss	S <sub>11</sub>			-10	dB
Switching Speed	T <sub>ON/OFF</sub>		1.0	5	uSec
Mute Noise Level	N <sub>MUTE</sub>			-160	dB/Hz
Noise Figure @ maximum gain	NF		10		dB
Third Order Intercept Point	IP3		+64		dBm
Harmonics @ Rated P <sub>1dB</sub> = 400W <sub>PK</sub>	H		-20		dBc
Spurious Signals	Spur		-70	-60	dBc
Supply Voltage (single phase)	V <sub>AC</sub>	100		240	Volt
Power Consumption @ 800W <sub>PK</sub>	P <sub>D</sub>			3000	Watt
Pulse Performance	T <sub>RISE (10-90)</sub>			200	ns
	T <sub>FALL(90-10)</sub>			200	ns
	P <sub>WIDTH</sub>	2			ms
	Duty cycle	10			%
	PRF	1.0 KHz			1.25 MHz
Pulse Overshoot				1	dB
Pulse Droop				1	dB

## MECHANICAL SPECIFICATIONS

Parameter	Value	Units	Limits
Dimensions H x W x L	19 x 8.75 x 22	Inch	Max
Weight	80	lb.	Max
RF Connectors	Type N Female (front or rear)		
Cooling	Built-in forced air cooling system		
LCD	Touchscreen Digital Display, including Fwd/Rev Power indication (dBm or Watt scale), Gain Adjustment, ALC Fast/Slow, On/Off, Standby mode, Fault indication, Rear panel HPIB IEEE-488.2 and Half Duplex RS-232 remote interface.		

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**ENVIRONMENTAL CHARACTERISTICS (Design to Meet)**

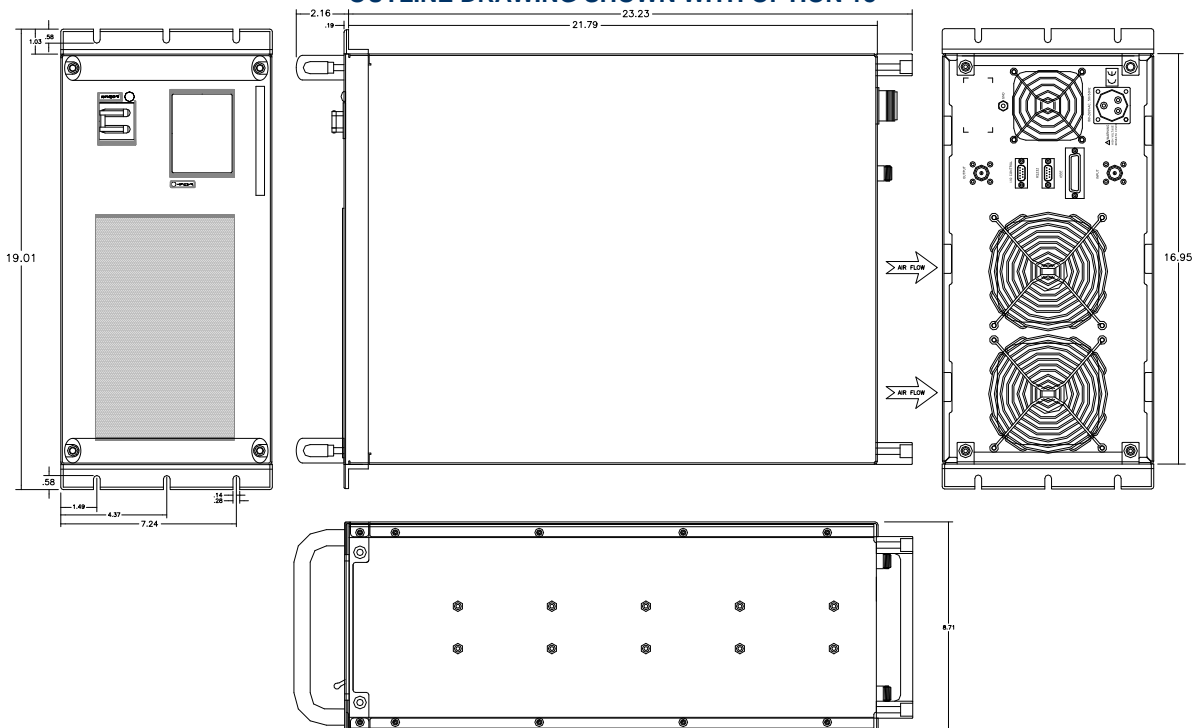
Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	$T_C$	0		+50	°C
Storage Temperature	$T_{STG}$	-40		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F Method 500.4)	ALT			30,000	Feet
Vibration/Shock MIL-STD-810F-Method 514.5/516.5 – Proc I	VI/SH		Airborne		

**PROTECTIONS**

Input Overdrive	+10 dBm	Max
Load VSWR @ $P_{OUT} = 800W_{PK}$	3:1 all phase and magnitude	-
Thermal Overload	85°C shutdown	Max

**I/O INTERFACE CONNECTOR – D-Sub 9-Pin, Female**

Pin #	Description	Specifications
1	Forward Test Point	Analog Voltage 0-5V <sub>DC</sub> relative to Forward Power Level
2	Reverse Test Point	Analog Voltage 0-5V <sub>DC</sub> relative to Reverse Power Level
3	5V Test Point	Test Point: +5.0V <sub>DC</sub> ±0.2V Test Point
4	N/C	No Connection
5	EXT Shutdown	Amplifier Disable: TTL Logic High (5V) (Internally Pulled-Low)
6	12V Test Point	Test Point: +12.0V <sub>DC</sub> ±0.5V
7	P/S Test Point	P/S Output Voltage 26.0V <sub>DC</sub> – 30.0V <sub>DC</sub>
8	GND	Ground
9	GND	Ground

**OUTLINE DRAWING SHOWN WITH OPTION 18**


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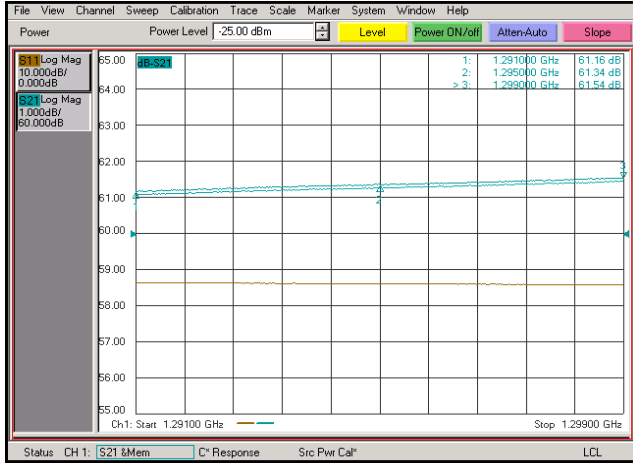
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**TYPICAL PERFORMANCE PLOTS**

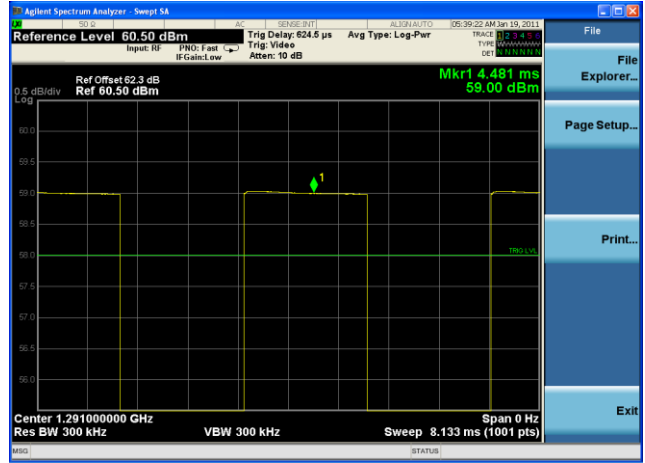
**Plot 1 – Small Signal Gain**

Top Curve: Small Signal Gain @  $P_{IN} = -25\text{dBm}$   
 Reference: 60dB, 1dB/div.  
 Bottom Curve: Input Return Loss  
 Reference: 0dB, 10dB/div.



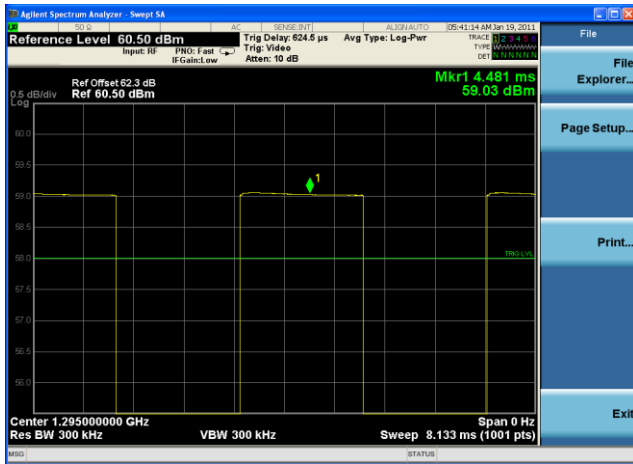
**Plot 2**

Power Output @ Pulse,  $P_{IN} = -1.56\text{dBm}$   
 CF = 1.291GHz, PW = 2ms, Duty Cycle = 50%  
 Reference: 60.5dBm, 0.5dB/div



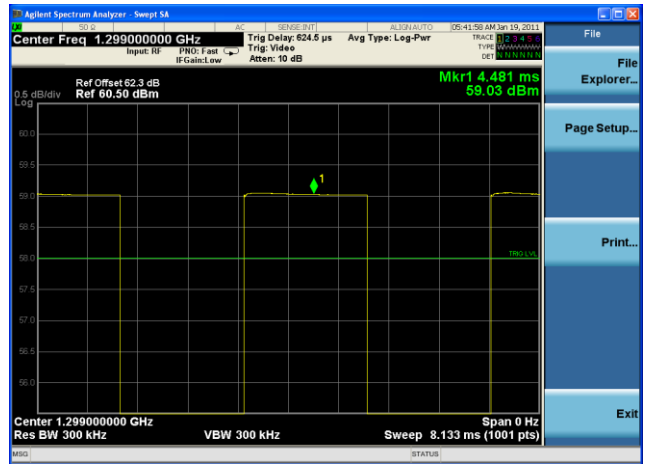
**Plot 3**

Power Output @ Pulse,  $P_{IN} = -1.56\text{dBm}$   
 CF = 1.295GHz, PW = 2ms, Duty Cycle = 50%  
 Reference: 60.5dBm, 0.5dB/div



**Plot 4**

Power Output @ Pulse,  $P_{IN} = -1.56\text{dBm}$   
 CF = 1.299GHz, PW = 2ms, Duty Cycle = 50%  
 Reference: 60.5dBm, 0.5dB/div



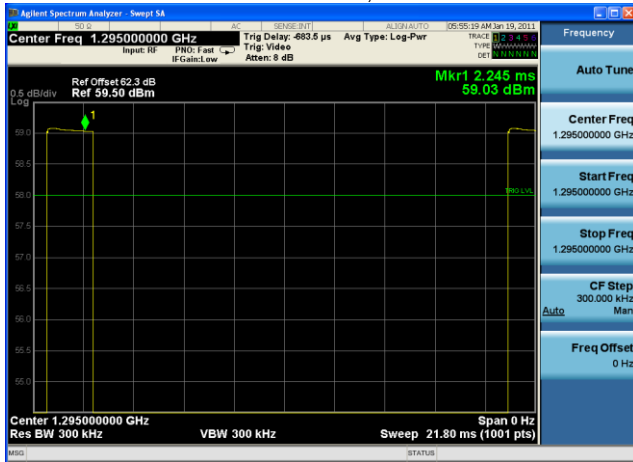
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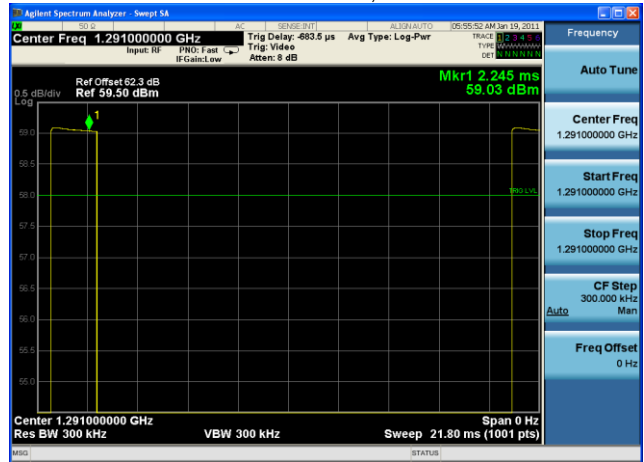
**Plot 5**

Power Output @ Pulse,  $P_{IN} = -1.9\text{dBm}$   
 CF = 1.295GHz, PW = 2ms, Duty Cycle = 10%  
 Reference: 59.5dBm, 0.5dB/div.



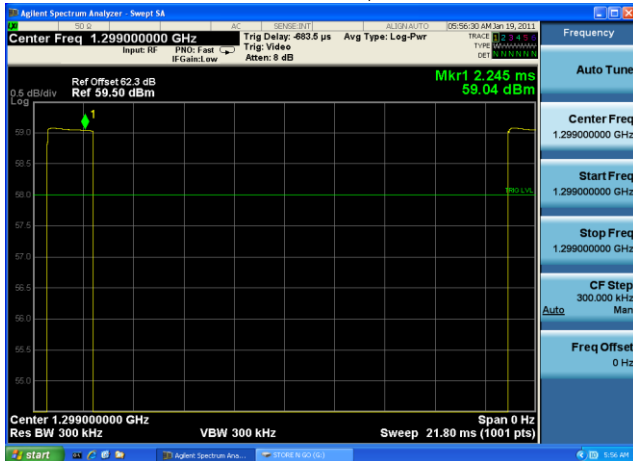
**Plot 6**

Power Output @ Pulse,  $P_{IN} = -1.66\text{dBm}$   
 CF = 1.291GHz, PW = 2ms, Duty Cycle = 10%  
 Reference: 59.5dBm, 0.5dB/div.



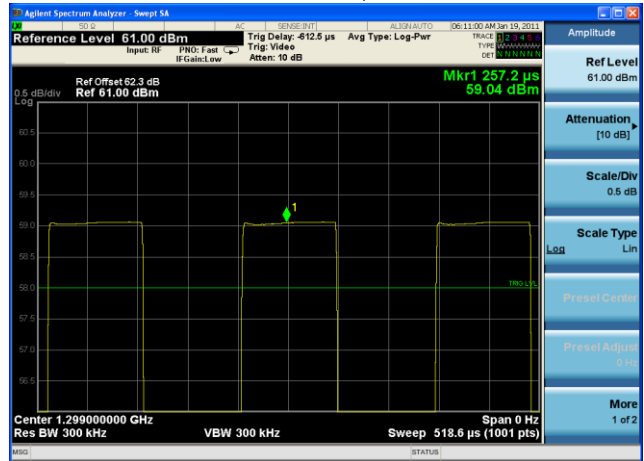
**Plot 7**

Power Output @ Pulse,  $P_{IN} = -2.0\text{dBm}$   
 CF = 1.299GHz, PW = 2ms, Duty Cycle = 10%  
 Reference: 59.5dBm, 0.5dB/div.



**Plot 8**

Power Output @ Pulse,  $P_{IN} = -1.76\text{dBm}$   
 CF = 1.299GHz, PW = 100us, Duty Cycle = 50%  
 Reference: 61dBm, 0.5dB/div.



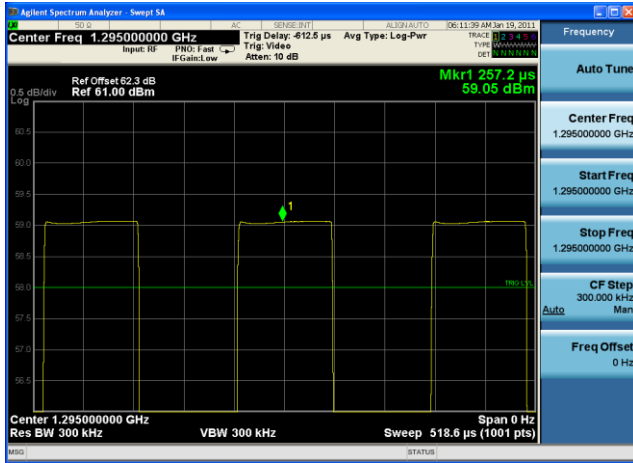
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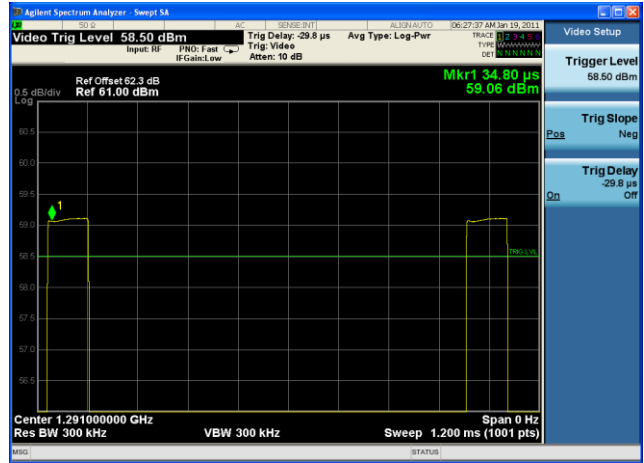
**Plot 9**

Power Output @ Pulse,  $P_{IN} = -1.5\text{dBm}$   
 CF = 1.295GHz, PW = 100us, Duty Cycle = 50%  
 Reference: 61dBm, 0.5dB/div.



**Plot 10**

Power Output @ Pulse,  $P_{IN} = -1.52\text{dBm}$   
 CF = 1.291GHz, PW = 100us, Duty Cycle = 10%  
 Reference: 61dBm, 0.5dB/div.



**Plot 11 – Noise Figure**

Top Curve: Noise Figure  
 Reference: 15dB, 1dB/div.  
 Bottom Curve: Small Signal Gain  
 Reference: 58dB, 1dB/div.

